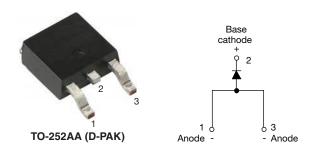


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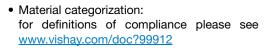
# Surface Mount Fast Soft Recovery Rectifier Diode, 8 A



PRODUCT SUMMARY						
Package	TO-252AA (D-PAK)					
I <sub>F(AV)</sub>	8 A					
V <sub>R</sub>	1000 V, 1200 V					
V <sub>F</sub> at I <sub>F</sub>	1.3 V					
I <sub>FSM</sub>	150 A					
t <sub>rr</sub>	80 ns					
T <sub>J</sub> max.	150 °C					
Diode variation	Single die					
Snap factor	0.6					

#### **FEATURES**

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C







ROHS COMPLIANT HALOGEN FREE

#### **APPLICATIONS**

- Output rectification and freewheeling diode in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

#### **DESCRIPTION**

The VS-8EWF..S-M3 fast soft recovery rectifier series has been optimized for combined short reverse recovery time, low forward voltage drop and low leakage current.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I <sub>F(AV)</sub>	Sinusoidal waveform	8	А					
V <sub>RRM</sub>		1000/1200	V					
I <sub>FSM</sub>		150	А					
V <sub>F</sub>	8 A, T <sub>J</sub> = 25 °C	1.3	V					
t <sub>rr</sub>	1 A, 100 A/µs	80	ns					
T <sub>J</sub>	Range	-40 to +150	°C					

VOLTAGE RATINGS								
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA					
VS-8EWF10S-M3	1000	1100	4					
VS-8EWF12S-M3	1200	1300	4					

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum average forward current	I <sub>F(AV)</sub>	T <sub>C</sub> = 96 °C, 180° conduction half sine wave	8				
Maximum peak one cycle	l	10 ms sine pulse, rated V <sub>RRM</sub> applied	125	Α			
non-repetitive surge current	I <sub>FSM</sub>	10 ms sine pulse, no voltage reapplied	150				
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	78	A <sup>2</sup> s			
waxiinum i-t for fusing	1-1	10 ms sine pulse, no voltage reapplied	110	A-5			
Maximum I <sup>2</sup> √t for fusing	I <sup>2</sup> √t	t = 0.1 ms to 10 ms, no voltage reapplied	1100	A <sup>2</sup> √s			



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS			
Maximum forward voltage drop	$V_{FM}$	8 A, T <sub>J</sub> = 25 °C		1.3	V			
Forward slope resistance	r <sub>t</sub>	T <sub>.1</sub> = 150 °C		25.6	mΩ			
Threshold voltage	V <sub>F(TO)</sub>	1J = 150 C		0.93	V			
Maximum reverse leakage current	1	T <sub>J</sub> = 25 °C	T <sub>J</sub> = 25 °C		mA			
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	$V_R = Rated V_{RRM}$	4	IIIA			

RECOVERY CHARACTERISTICS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	· •		
Reverse recovery time	t <sub>rr</sub>	I <sub>F</sub> at 8 A <sub>pk</sub>	270	ns	I <sub>FM</sub>		
Reverse recovery current	I <sub>rr</sub>	25 A/μs	4.2	Α	$t_a \mid t_b \mid$		
Reverse recovery charge	Q <sub>rr</sub>	T <sub>J</sub> = 25 °C	1	μC	di/ dt Q		
Snap factor	S		0.6		l I I I I I I I I I I I I I I I I I I I		

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C
Maximum thermal resistance, unction to case	R <sub>thJC</sub>	DC operation	2.5	°C/W
Typical thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub> (1)		50	C/VV
Soldering temperature	T <sub>S</sub>	For 10 s	260	°C
Annyayimata waisht			1	g
Approximate weight			0.03	OZ.
Applicate devices		Consisted TO 252AA (D. DAIV)	8EWF10S	
Marking device		Case style TO-252AA (D-PAK)	8EWF12S	

#### Note

<sup>(1)</sup> When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 µm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

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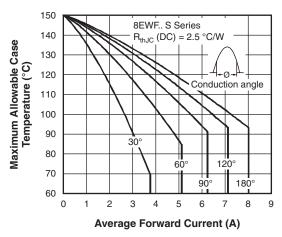


Fig. 1 - Current Rating Characteristics

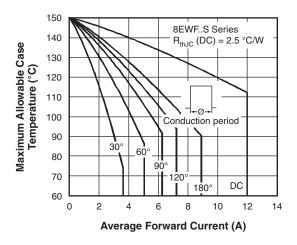


Fig. 2 - Current Rating Characteristics

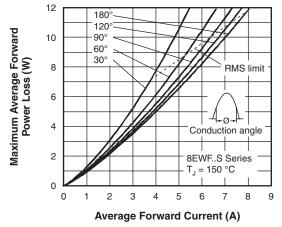


Fig. 3 - Forward Power Loss Characteristics

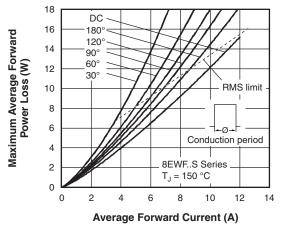


Fig. 4 - Forward Power Loss Characteristics

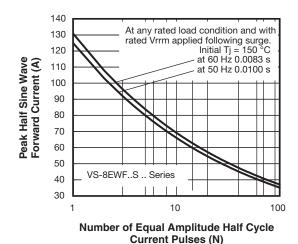


Fig. 5 - Maximum Non-Repetitive Surge Current

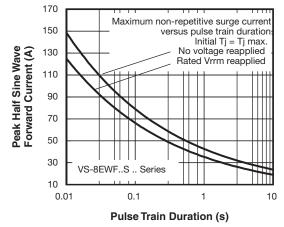


Fig. 6 - Maximum Non-Repetitive Surge Current



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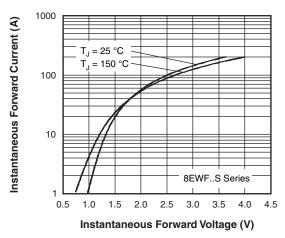


Fig. 7 - Forward Voltage Drop Characteristics

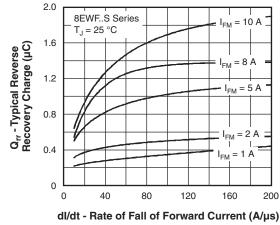


Fig. 10 - Recovery Charge Characteristics, T<sub>J</sub> = 25 °C

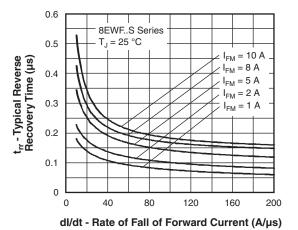


Fig. 8 - Recovery Time Characteristics, T<sub>J</sub> = 25 °C

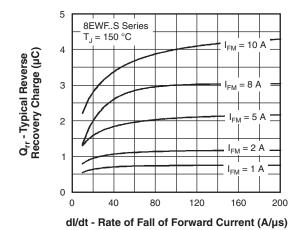


Fig. 11 - Recovery Charge Characteristics, T<sub>J</sub> = 150 °C

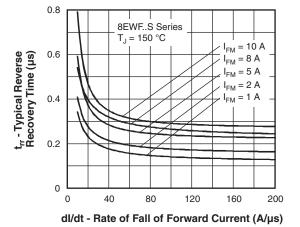


Fig. 9 - Recovery Time Characteristics,  $T_J = 150 \, ^{\circ}\text{C}$ 

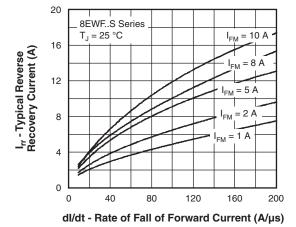
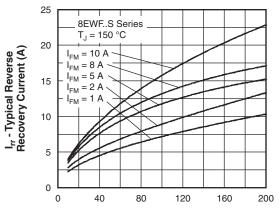


Fig. 12 - Recovery Current Characteristics, T<sub>J</sub> = 25 °C

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dl/dt - Rate of Fall of Forward Current (A/µs)

Fig. 13 - Recovery Current Characteristics, T<sub>J</sub> = 150 °C

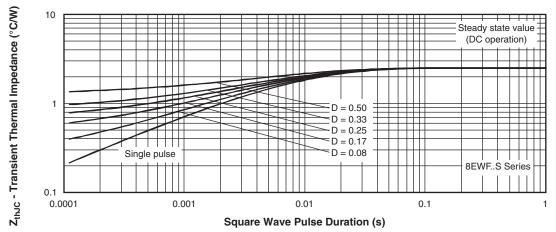
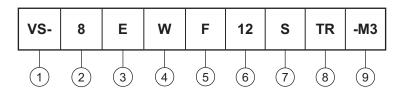


Fig. 14 - Thermal Impedance Z<sub>thJC</sub> Characteristics

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#### **ORDERING INFORMATION TABLE**

Device code



- 1 Vishay Semiconductors product
- Current rating (8 = 8 A)
- 3 Circuit configuration:
  - E = single diode
- 4 Package:
  - W = D-PAK
- 5 Type of silicon:
  - F = fast soft recovery rectifier
- Voltage code x 100 = V<sub>RRM</sub> 10 = 1000 V 12 = 1200 V
- 7 S = surface mountable
- 8 • TR = tape and reel
  - TRR = tape and reel (right oriented)
  - TRL = tape and reel (left oriented)
- 9 Environmental digit:
  - -M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-8EWF10S-M3	75	3000	Antistatic plastic tubes					
VS-8EWF10STR-M3	2000	2000	13" diameter reel					
VS-8EWF10STRL-M3	3000	3000	13" diameter reel					
VS-8EWF10STRR-M3	3000	3000	13" diameter reel					
VS-8EWF12S-M3	75	3000	Antistatic plastic tubes					
VS-8EWF12STR-M3	2000	2000	13" diameter reel					
VS-8EWF12STRL-M3	3000	3000	13" diameter reel					
VS-8EWF12STRR-M3	3000	3000	13" diameter reel					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					
SPICE model	www.vishay.com/doc?95552					



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**NOTES** 

3

2

MAX.

0.410

0.070

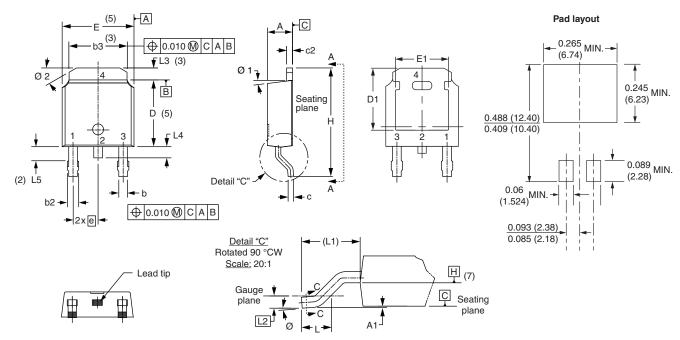
0.050

0.040

0.060

# **D-PAK (TO-252AA)**

#### **DIMENSIONS** in millimeters and inches



Ī	SYMBOL	MILLIMETERS		INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		
	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STMBOL	MIN.	MAX.	MIN.	MAX
ſ	Α	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	BSC
ſ	A1	-	0.13		0.005			Н	9.40	10.41	0.370	0.41
Ī	b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.07
Ī	b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	REF.
ſ	b3	4.95	5.46	0.195	0.215	3		L2	0.51 BSC		0.020 BSC	
Ī	С	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.05
Ī	c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.04
ſ	D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.06
Ī	D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°
ſ	Е	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°
Ī	E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°

#### Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- Lead dimension uncontrolled in L5
- Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad
- Section C C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip
- Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- Dimension b1 and c1 applied to base metal only
- (7) Datum A and B to be determined at datum plane H
- Outline conforms to JEDEC outline TO-252AA



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